



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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Gundt a  
A. Z. Z.  
7/8/03

In re Patent Application of

SOTOME, Yoshihiro

Atty. Ref.: 900-410

Serial No. 10/038,680

Group: 2825

Filed: January 8, 2002

Examiner: Lee, Calvin

For: METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE AND THE  
SEMICONDUCTOR DEVICE MANUFACTURED BY THE METHOD

\* \* \* \* \*

July 1, 2003

Assistant Commissioner for Patents  
Washington, DC 20231

Sir:

AMENDMENT

Responsive to the Official Action dated April 2, 2003, please amend the  
above-identified application as follows:

IN THE CLAIMS

Please substitute the following amended claim(s) for corresponding claim(s)  
previously presented. A copy of the amended claim(s) showing current revisions is  
attached.

1. (*Unamended*) A method of manufacturing a semiconductor device comprising  
steps of:

forming a first metal film having a reducing property on a semiconductor  
substrate;

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